

AOZ8073

4-Line EMI Filter with Integrated ESD Protection

General Description

The AOZ8073 is an 4-line device integrating EMI filtering with ESD protection for each line. It is designed to suppress unwanted EMI/RFI signals and provide electrostatic discharge (ESD) protection in portable electronic equipment. This state-of-the-art device utilizes AOS leading edge Trench Vertical Structure [TVS]²™ technology for superior clamping performance and filter attenuation over the full operating display range. The AOZ8073 has been optimized for protection of color LCD displays and CCD camera lines in cellular phones and other portable consumer electronic devices.

The AOZ8073 consists of four identical circuits comprised of TVS diodes for ESD protection, and a resistor–capacitor network for EMI/RFI filtering. A series resistor value of 100Ω and a capacitance value of 8pF are used to achieve -20dB minimum attenuation from 700MHz to 3.0GHz. The TVS diodes provide effective suppression of ESD voltages in excess of ±15kV (air discharge) and ±15kV (contact discharge). This exceeds IEC 61000-4-2, level 4 ESD immunity test.

The AOZ8073 comes in an RoHS compliant, 1.2mm x 1.8mm, 0.4mm pitch DFN package and is rated over a -40°C to +85°C ambient temperature range.

Features

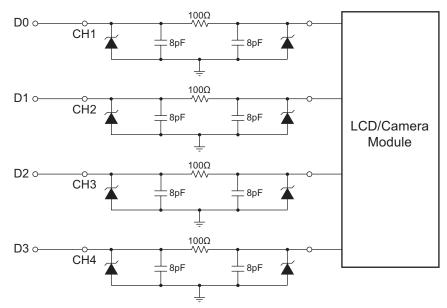
- 4 lines for EMI filtering and ESD protection:
 - Exceeds IEC 61000-4-2, level 4 (ESD) immunity test
 - $-\pm15kV$ (air discharge) and $\pm15kV$ (contact discharge)
- Trench Vertical Structure [TVS]² ™ based technology used to achieve excellent ESD clamping & filter performance over the full operating display range
- Filter performance: -20db attenuation from 700MHz to 3.0GHz
- Low operating voltage: 5.0V
- Capacitance stability over wide range of voltages and temperatures
- DFN package: 1.2mm x 1.8mm, 0.4mm pitch
- Pb-Free device

Applications

- EMI filtering and ESD protection for data lines
- LCD displays, camera interface, I/O interface
- Portable handheld devices, cell phones, PDA phones



Typical Application





Ordering Information

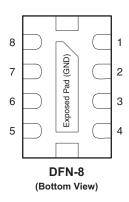
Part Number	Ambient Temperature Range	Package	Environmental		
AOZ8073DI	-40°C to +85°C	DFN-8	Green Product		

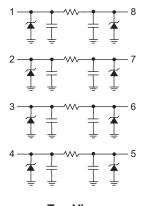


AOS Green Products use reduced levels of Halogens, and are also RoHS compliant.

Please visit www.aosmd.com/web/quality/rohs_compliant.jsp for additional information.

Pin Configuration





Top View

Pin Number Pin Name Pin Function CH 1 **Channel 1 Connections** 1, 8 CH 2 2,7 **Channel 2 Connections** CH 3 **Channel 3 Connections** 3, 6 4, 5 CH 4 **Channel 4 Connections** GND Exposed Pad **Common Ground Connection**

Pin Description



Absolute Maximum Ratings

Exceeding the Absolute Maximum ratings may damage the device.

Parameter	Rating
Storage Temperature (T _S)	-65°C to +150°C
ESD Rating per IEC61000-4-2, contact ⁽¹⁾	±15kV
ESD Rating per IEC61000-4-2, air ⁽¹⁾	±15kV
ESD Rating per Human Body Model ⁽²⁾	±30kV

Notes:

1. IEC 61000-4-2 discharge with C_Discharge = 150pF, R_Discharge = 330 \Omega.

2. Human Body Discharge per MIL-STD-883, Method 3015 C_{Discharge} = 100pF, R_{Discharge} = 1.5k Ω .

Electrical Characteristics

 $T_A = 25^{\circ}C$ unless otherwise specified.

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Units
V _{RWM}	Reverse Working Voltage	(3)			5.0	V
V _{BR}	Reverse Breakdown Voltage	$I_{T} = 1 m A^{(4)}$	6	7	8	V
I _R	Reverse Leakage Current	V _{RWM} = 3.3V			0.1	μA
V _{CL}	Signal Clamp Voltage	I _{LOAD} = 1A, positive clamp ⁽⁵⁾⁽⁸⁾ I _{LOAD} = 1A, negative clamp ⁽⁵⁾⁽⁸⁾			9.0 -2.5	V
		I _{LOAD} = 5A, positive clamp ⁽⁵⁾⁽⁸⁾ I _{LOAD} = 5A, negative clamp ⁽⁵⁾⁽⁸⁾			11.5 -3.5	
		I _{LOAD} = 12A, positive clamp ⁽⁵⁾⁽⁸⁾ I _{LOAD} = 12A, negative clamp ⁽⁵⁾⁽⁸⁾			14.0 -5.0	
R _{CH}	Total Series Resistance	I _R = 20mA	90	100	110	Ω
C _{CH}	Channel Capacitance	Input to Ground ⁽⁶⁾⁽⁷⁾⁽⁸⁾	7	8	9	pF
f _C	Cut-off Frequency	Measured with 50 Ω source and 50 Ω load termination		220		MHz
	Attenuation from 700MHz to 3.0GHz	$V_R = 0V$ Measured with 50 Ω source and 50 Ω load termination		-20		dB

Notes:

3. The working peak reverse voltage, V_{RWM} , should be equal to or greater than the DC or continuous peak operating voltage level.

4. V_{BR} is measured at the pulse test current I_T.

5. Measurements performed using a 100ns Transmission Line Pulse (TLP) system.

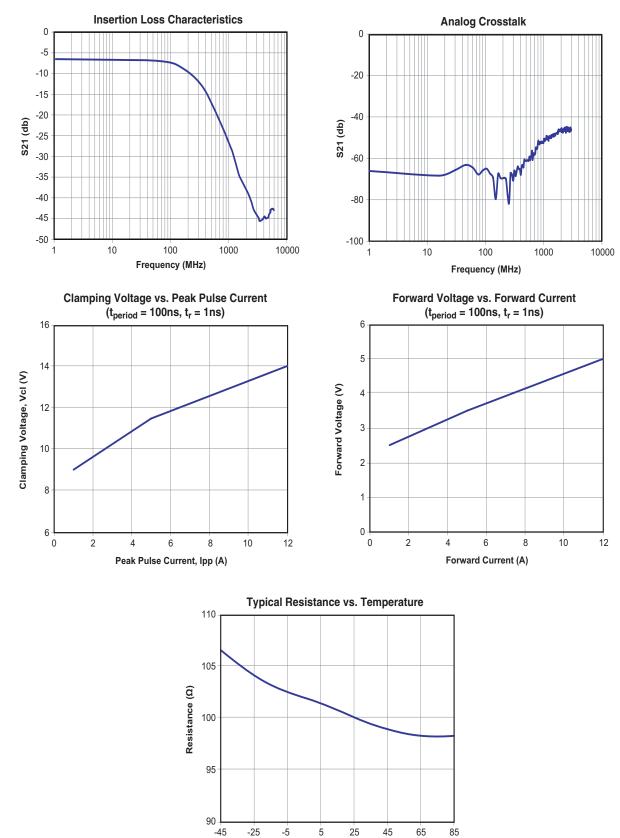
6. Total capacitance is equal to $2 \times C_{CH}$.

7. Measured at 25°C, $V_R = 2.5V$, f = 1.0MHz.

8. Guaranteed by design.

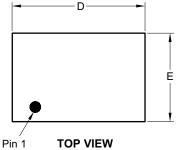


Typical Performance Characteristics

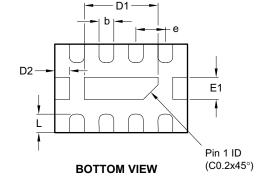


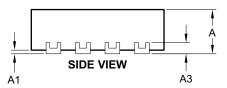
Temparature (°C)

Package Dimensions, DFN 1.2 x 1.8, 8L

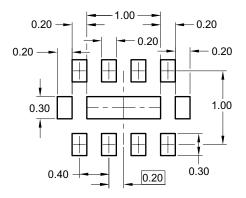


Pin 1 IOP V Marking





RECOMMENDED LAND PATTERN



Dimensions in millimeters					
Symbols	Min.	Nom.	Max.		Syı
А	0.50	0.55	0.60		
A1	0.00	_	0.05		
A3	0).152 Re	f.		
b	0.15	0.20	0.25		
D	1.75	1.80	1.85		
D1	0.95	1.00	1.05		
D2	0				
E	1.15	1.20	1.25		
E1	0.25	0.30	0.35		
е	(
L	0.20	0.25	0.30		

Dimensions in inches

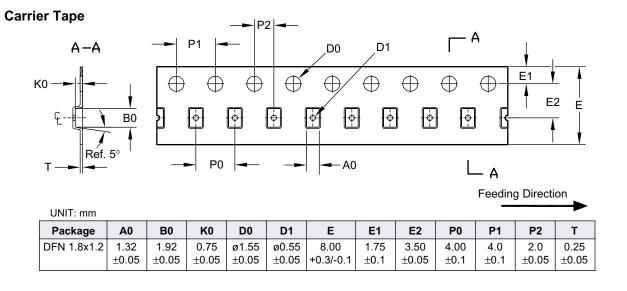
5	-	Dimensions in menes									
	Syr	nbols	Min.	Nom.	Max.						
)		А	0.020	0.022	0.024						
;		A1	0.000	_	0.002						
		A3	0.006 Ref.								
;		b	0.006	0.008	0.010						
;		D	0.069	0.071	0.073						
;		D1	0.037	0.039	0.041						
		D2	0.008 Ref.								
;		Е	0.045	0.047	0.049						
;		E1	0.010	0.012	0.014						
		е	0.016 BSC								
)		L	0.008	0.010	0.012						
		е	0	.016 BS	С						

Notes:

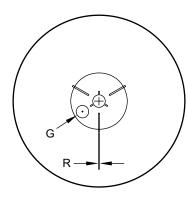
- 1. Controlling dimension is millimeter, converted inch dimensions are not necessaily exact.
- 2. Warpage shall not exceed 0.10mm.
- 3. Marking is for package orientation reference only.

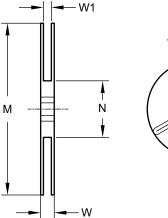


Tape and Reel Dimensions, DFN 1.2 x 1.8, 8L



Reel



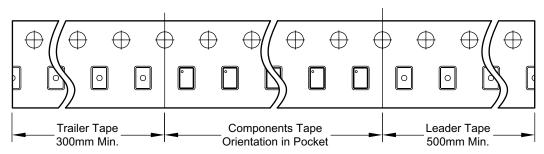


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UNIT: mm

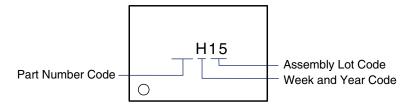
Tape Size	Reel Size	М	N	W	W1	н	S	к	G	R
8mm	ø178	ø178.0 ±1.0	ø60.0 ±1.0	11.80 ±0.5		ø13.0 +0.5/-0.2	2.40 ±0.10	10.25 ±0.2	ø9.8	

Leader / Trailer & Orientation





Part Marking



This data sheet contains preliminary data; supplementary data may be published at a later date. Alpha & Omega Semiconductor reserves the right to make changes at any time without notice.

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